# **CPEC** Tracking System Optimization

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On behalf of the CEPC Tracker Team

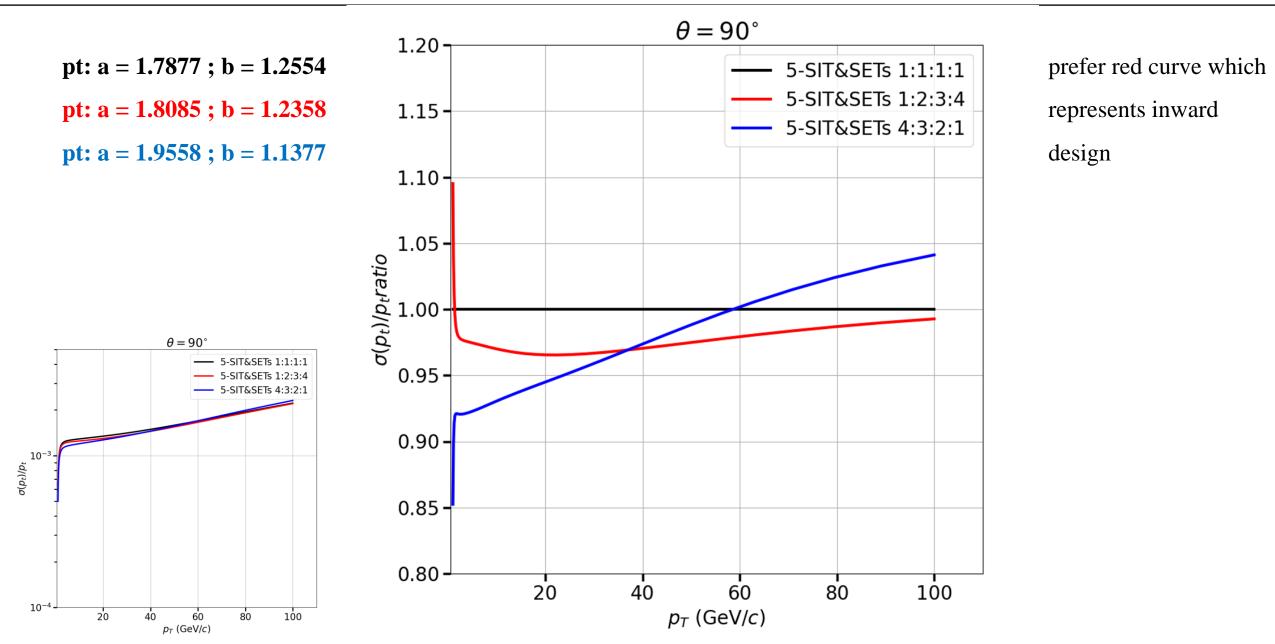
2021.12.10

- 1. Optimization on SITs for full Silicon Tracker
- 2. Optimization on DC radius for Forth CEPC Tracker
- 3. Optimization on number of SITs for Forth CEPC Tracker

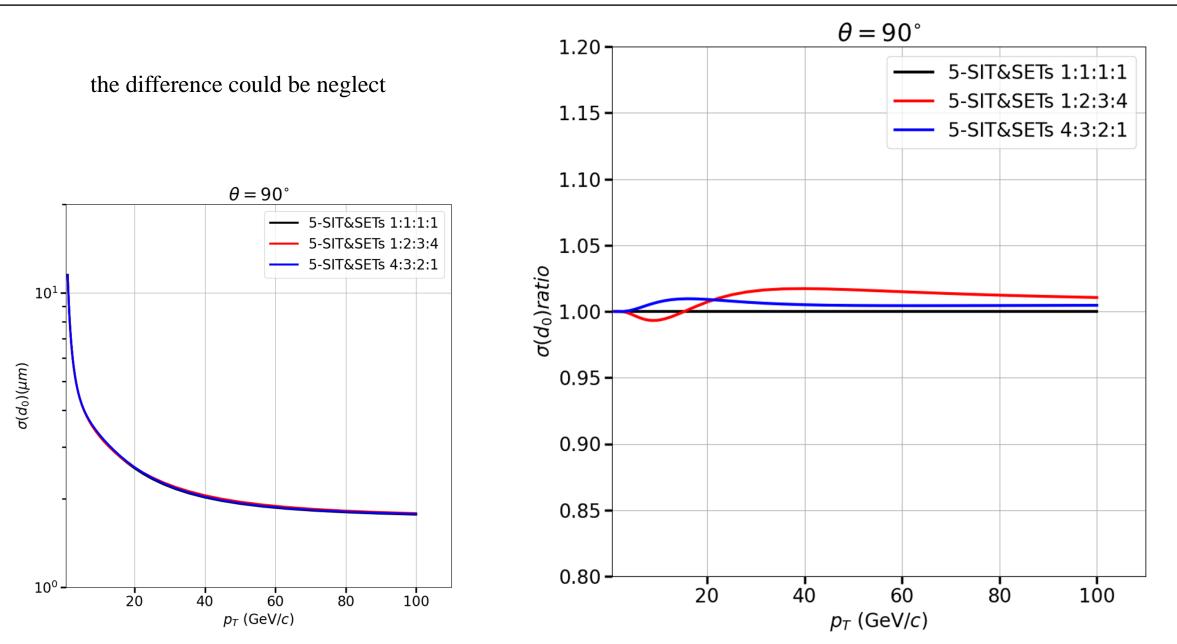
#### table shows the main parameters of each geometry layer while the red parts need to be optimized

Layers	Radius(mm)	$\sigma_{R\phi}(\mathrm{mu})$	$\sigma_Z(\mathrm{mu})$	Thickness $(1/X_0)$
Beam Tube	14.5	-	-	0.0015
VTX	16/18/37/39/58/60	2.8/6/4/4/4/4	2.8/6/4/4/4/4	0.001
Support for each VTX layer	-	-	-	0.001
VTX-shell	65.0	-	-	0.0015
SIT&SETs	///	7.2//7.2	86.6//86.6	0.0065

### 1. Optimization on SITs for full Silicon Tracker



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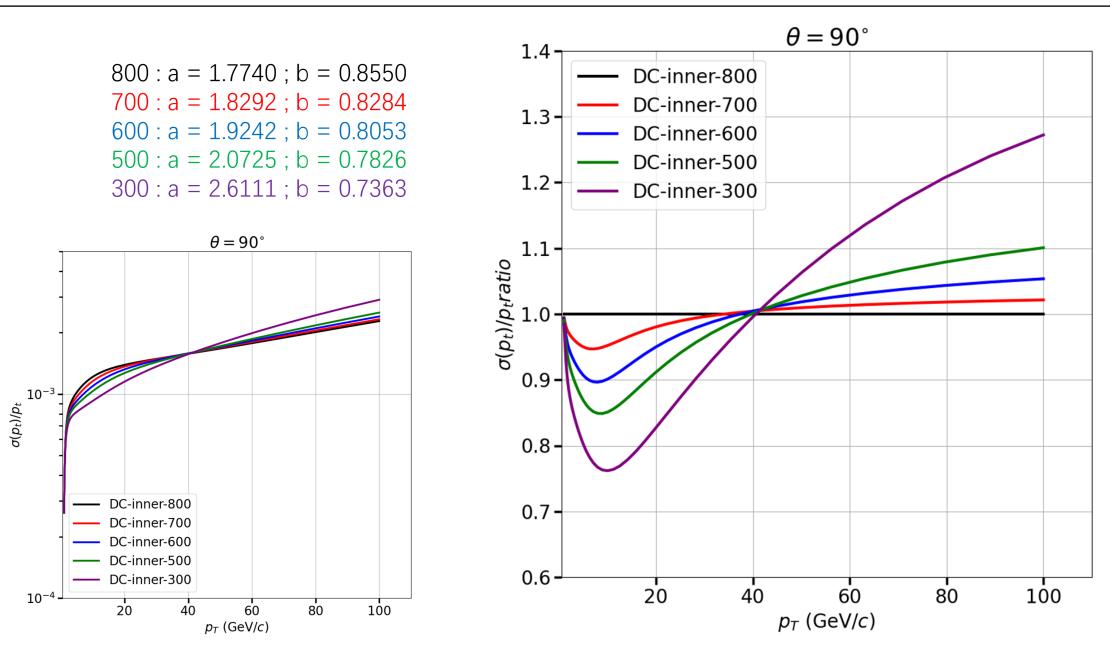


# 2. Optimization on DC radius for Forth CEPC Tracker

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Layers	Radius(mm)	$\sigma_{R\phi}(\mathrm{mu})$	$\sigma_Z(\mathrm{mu})$	Thickness $(1/X_0)$
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Support for each VTX layer	-	-	-	0.001
VTX-shell	65.0	-	-	0.0015
SITs	inward design (1:2:3)	7.2//7.2	86.6//86.6	0.0065
DC inner shell		-	-	0.00104
DC wires (15*15mm) and gas		100	2828	0.000081+0.0000413
DC outer shell	1803.0	-	-	0.01346
SET	1811.0	7.2	86.6	0.0065

### 2. Optimization on DC radius for Forth CEPC Tracker

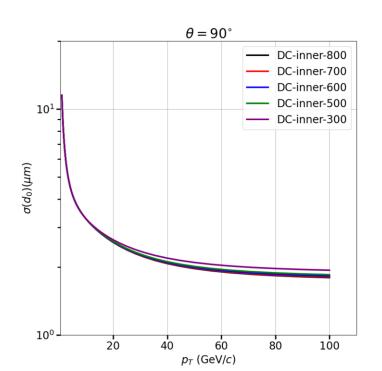


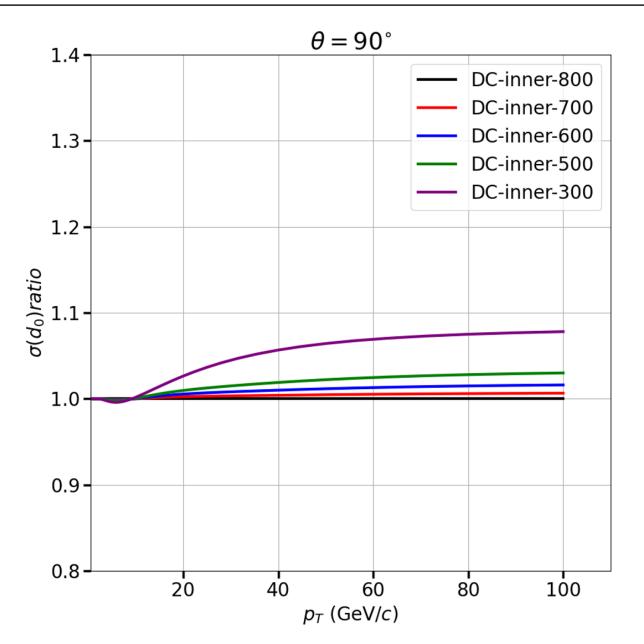
# 2. Optimization on DC radius for Forth CEPC Tracker

the difference could be neglect except the purple

curve

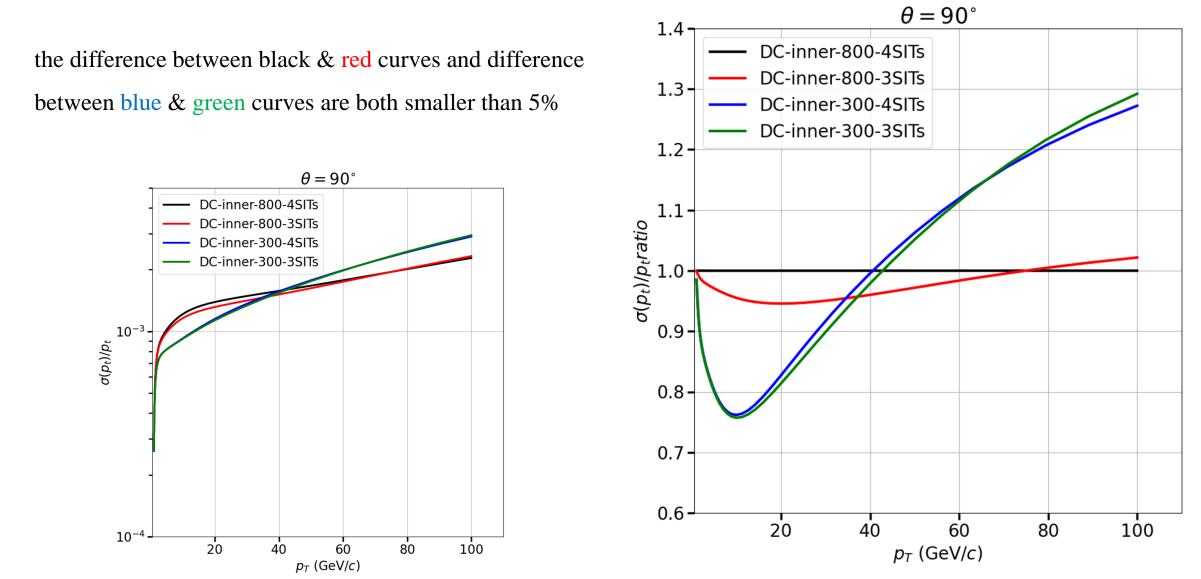
DC-inner-300 gets such worse resolution of  $d_0$ because the silicon detectors are too much close to beam pipe together





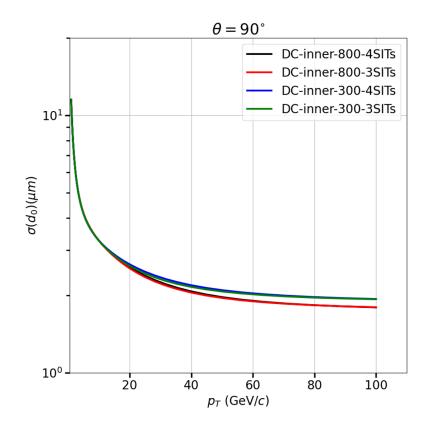
## 3. Optimization on number of SITs for Forth CEPC Tracker

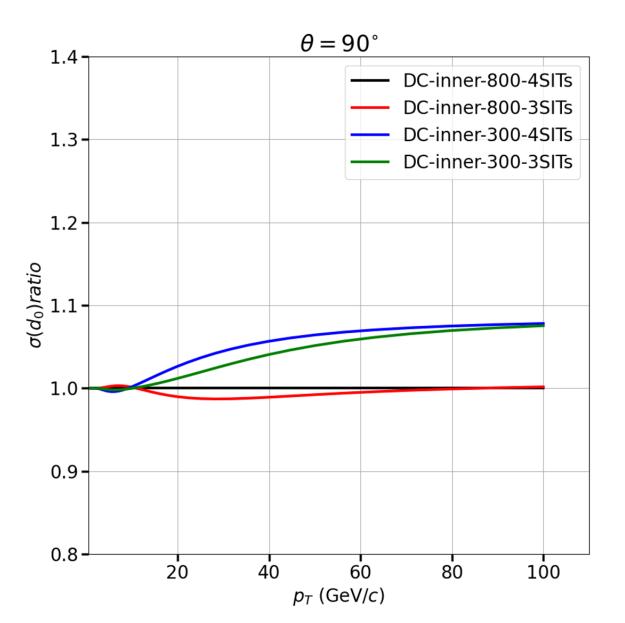
following the section-2, the number of SITs is decreased from 4 to 3, while the SITs keep inward design



## 3. Optimization on number of SITs for Forth CEPC Tracker

the difference between black & red curves and difference between blue & green curves are both smaller than 5%





- 1. Inward design on SITs could take better resolution of momentum because of less multiple scattering influence;
- 2. The bigger drift chamber, the better resolution of low momentum, but the worse resolution of high momentum and  $d_0$ ;
- 3. Since the resolution changes of momentum and  $d_0$  are both smaller than 5%, the number of SITs is going to be decreased from 4 to 3, to save one silicon layer.